

# Intercorrelated In-Plane and Out-of-Plane Ferroelectric Layered Semiconductor In<sub>2</sub>Se<sub>3</sub>

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Citation Report

#	ARTICLE	IF	CITATIONS
2	Multidirection Piezoelectricity in Mono- and Multilayered Hexagonal $\text{In}_2\text{Se}_3$ . ACS Nano, 2018, 12, 4976-4983.	7.3	215
3	Study of Internal Morphology on Preparation of $\text{Cu}_2\text{O}$ Thin-Plate using Thermal Oxidation. Journal of Physics: Conference Series, 2018, 1116, 042046.	0.3	7
4	Ferroelectric resistive switching behavior in two-dimensional materials/ $\text{BiFeO}_3$ hetero-junctions. Nanoscale, 2018, 10, 23080-23086.	2.8	24
5	Atomic-scale mapping of interface reconstructions in multiferroic heterostructures. Applied Physics Reviews, 2018, 5, .	5.5	23
6	Temperature-dependent growth of few layer $\text{In}_2\text{Se}_3$ and $\text{In}_2\text{Se}_3$ single crystals for optoelectronic device. Semiconductor Science and Technology, 2018, 33, 125002.	1.0	29
7	Room-Temperature Ferroelectricity in Hexagonally Layered $\text{In}_2\text{Se}_3$ Nanoflakes down to the Monolayer Limit. Advanced Functional Materials, 2018, 28, 1803738.	7.8	241
8	Molecular-Beam Epitaxy of Two-Dimensional $\text{In}_2\text{Se}_3$ and Its Giant Electroresistance Switching in Ferroresistive Memory Junction. Nano Letters, 2018, 18, 6340-6346.	4.5	163
9	Room-temperature ferroelectricity and a switchable diode effect in two-dimensional $\text{In}_2\text{Se}_3$ thin layers. Nanoscale, 2018, 10, 14885-14892.	2.8	173
10	Ferroelectric Field-Effect Transistors Based on $\text{MoS}_2$ and $\text{CuInP}_2\text{S}_6$ Two-Dimensional van der Waals Heterostructure. ACS Nano, 2018, 12, 6700-6705.	7.3	246
11	Two-dimensional materials with piezoelectric and ferroelectric functionalities. Npj 2D Materials and Applications, 2018, 2, .	3.9	258
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16	Controlled Crystal Growth of Indium Selenide, $\text{In}_2\text{Se}_3$ , and the Crystal Structures of $\text{In}_2\text{Se}_3$ . Inorganic Chemistry, 2018, 57, 11775-11781.	1.9	97
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21	Gate-Tunable In-Plane Ferroelectricity in Few-Layer SnS. Nano Letters, 2019, 19, 5109-5117.	4.5	129
22	Probing Effective Out-of-Plane Piezoelectricity in van der Waals Layered Materials Induced by Flexoelectricity. Small, 2019, 15, e1903106.	5.2	29
23	Ferroelectric properties of gradient doped Y <sub>2</sub> O <sub>3</sub> :HfO <sub>2</sub> thin films grown by pulsed laser deposition. Applied Physics Letters, 2019, 115, .	1.5	9
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59	Atomically Resolving Polymorphs and Crystal Structures of $\text{In}_2\text{Se}_3$ . Chemistry of Materials, 2019, 31, 10143-10149.	3.2	71
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331	ĐĐ°Ñ€Đ°Đ°Ñ,ĐμÑ€Đ,ÑÑ,Đ,Đ°Đ° Đ½Đ°Đ½Đ½Đ¾ÑÑ,Ñ€ÑfĐ°Ñ,ÑfÑ€Đ¾Đ²Đ°Đ½Đ,Ñ... Đ²Đ°Đ»ÑŽÑ±ĐμĐ½Ñ€ In6Se7 Ñf ÑĐ°Ñ€ÑfĐ		
332	Two-dimensional ABC <sub>3</sub> (A = Sc, Y; B = Al, Ga, In; C = S, Se, Te) with intrinsic electric field for photocatalytic water splitting. <i>International Journal of Hydrogen Energy</i> , 2023, 48, 5929-5939.	3.8	6
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343	Ferro-piezoelectricity in emerging Janus monolayer BMX <sub>2</sub> (M = Ga, In and X = S, Se): <i>in</i> investigations. <i>Nanoscale Advances</i> , 2023, 5, 1425-1432.	2.2	5
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